

January 2008

74LVT574, 74LVTH574 Low Voltage Octal D-Type Flip-Flop with 3-STATE Outputs

Features

- Input and output interface capability to systems at 5V V_{CC}
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH574), also available without bushold feature (74LVT574)
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink -32mA/+64mA
- Functionally compatible with the 74 series 574
- Latch-up performance exceeds 500mA
- ESD performance:
 - Human-body model > 2000V
 - Machine model > 200V
 - Charged-device model > 1000V

General Description

The LVT574 and LVTH574 are high-speed, low-power octal D-type flip-flop featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable (\overline{OE}) are common to all flip-flops.

The LVTH574 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These octal flip-flops are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT574 and LVTH574 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Ordering Information

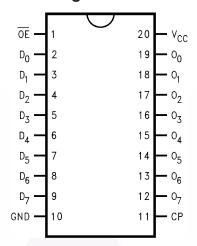
Order Number	Package Number	Package Description
74LVT574WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVT574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVT574MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), JEDEC MO-150, 5.3mm Wide
74LVT574MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH574WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LVTH574SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVTH574MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), JEDEC MO-150, 5.3mm Wide
74LVTH574MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.



All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagram



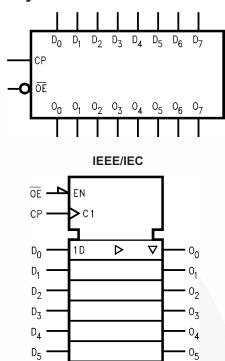
Pin Description

Pin Names	Description
D ₀ –D ₇	Data Inputs
СР	Clock Pulse Input
ŌĒ	3-STATE Output Enable Input
O ₀ –O ₇	3-STATE Outputs

Functional Description

The LVT574 and LVTH574 consist of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D-type inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable (\overline{OE}) LOW, the contents of the eight flip-flops are available at the outputs. When the \overline{OE} is HIGH, the outputs go to the high impedance state. Operation of the \overline{OE} input does not affect the state of the flip-flops.

Logic Symbols



Truth Table

 D_6

 D_7

	Outputs		
D _n	СР	ŌĒ	O _n
Н	_	L	Н
L	_	L	L
Х	L	L	O _o
Х	Х	Н	Z

06

07

H = HIGH Voltage Level

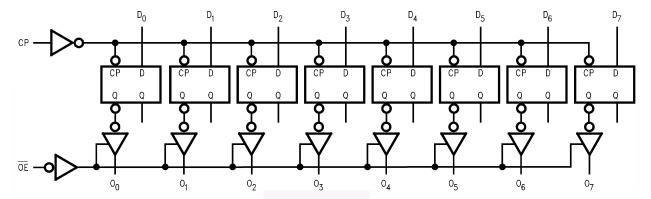
L = LOW Voltage Level

X = Immaterial

Z = High Impedance

O_o = Previous O_o before HIGH to LOW of CP

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating		
V _{CC}	Supply Voltage	-0.5V to +4.6V		
V _I	DC Input Voltage	-0.5V to +7.0V		
Vo	DC Output Voltage			
	Output in 3-STATE	-0.5V to +7.0V		
	Output in HIGH or LOW State ⁽¹⁾	-0.5V to +7.0V		
I _{IK}	DC Input Diode Current, V _I < GND			
I _{OK}	DC Output Diode Current, V _O < GND			
Io	DC Output Current, V _O > V _{CC}			
	Output at HIGH State	64mA		
	Output at LOW State	128mA		
I _{CC}	DC Supply Current per Supply Pin	±64mA		
I _{GND}	DC Ground Current per Ground Pin ±128			
T _{STG}	Storage Temperature	−65°C to +150°C		

Note:

1. IO Absolute Maximum Rating must be observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min	Max	Units
V _{CC}	Supply Voltage	2.7	3.6	V
VI	Input Voltage	0	5.5	V
I _{OH}	HIGH-Level Output Current		-32	mA
I _{OL}	LOW-Level Output Current		64	mA
T _A	Free-Air Operating Temperature		85	°C
Δt / ΔV	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V	0	10	ns/V

DC Electrical Characteristics

	Parameter Input Clamp Diode Voltage		V _{CC} (V)		T _A = -	40°C to +	85°C	Units
Symbol				Conditions	Min.	Typ. ⁽²⁾	Max.	
V _{IK}			2.7	$I_I = -18\text{mA}$			-1.2	V
V _{IH}	Input HIGH Vol	tage	2.7–3.6	$V_0 \le 0.1V$ or	2.0			V
V _{IL}	Input LOW Voltage		2.7–3.6	$V_O \ge V_{CC} - 0.1V$			0.8	V
V _{OH}	Output HIGH V	oltage/	2.7–3.6	$I_{OH} = -100 \mu A$	V _{CC} -0.2			V
			2.7	$I_{OH} = -8mA$	2.4			1
				$I_{OH} = -32 \text{mA}$	2.0			
V _{OL}	Output LOW Vo	oltage	2.7	$I_{OL} = 100 \mu A$			0.2	V
				I _{OL} = 24mA			0.5	1
			3.0	I _{OL} = 16mA			0.4	
				$I_{OL} = 32mA$			0.5	
				$I_{OL} = 64 \text{mA}$			0.55	1
I _{I(HOLD)} ⁽³⁾	Bushold Input I	Minimum	3.0	V _I = 0.8V	75			μA
	Drive			V _I = 2.0V	-75			
I _{I(OD)} (3)	Bushold Input	Over-Drive	3.0	(4)	500			μA
Current to Cha	nge State		(5)	-500				
I _I	Input Current		3.6	V _I = 5.5V			10	μA
		Control Pins Data Pins	3.6	$V_I = 0V \text{ or } V_{CC}$			±1	
			3.6	$V_I = 0V$			-5	
			$V_I = V_{CC}$			1		
I _{OFF}	Power Off Leal	kage Current	0	$0V \le V_1 \text{ or } V_0 \le 5.5V$			±100	μA
I _{PU/PD}	Power up/dowr Output Current		0–1.5	$V_O = 0.5V \text{ to } 3.0V,$ $V_I = \text{GND or } V_{CC}$			±100	μА
I _{OZL}	3-STATE Output Current	ut Leakage	3.6	$V_O = 0.5V$			-5	μA
l _{OZH}	3-STATE Output Current	ut Leakage	3.6	V _O = 3.0V			5	μA
I _{OZH} +	3-STATE Output Current	ut Leakage	3.6	$V_{CC} < V_O \le 5.5V$			10	μА
I _{CCH}	Power Supply Current		3.6	Outputs HIGH			0.19	mA
I _{CCL}	Power Supply Current		3.6	Outputs LOW	A		5	mA
I _{CCZ}	Power Supply Current		3.6	Outputs Disabled			0.19	mA
I _{CCZ} +	Power Supply Current		3.6	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled			0.19	mA
Δl _{CC}	Increase in Por Current ⁽⁶⁾	wer Supply	3.6	One Input at V _{CC} – 0.6V, Other Inputs at V _{CC} or GND			0.2	mA

Notes:

- 2. All typical values are at $V_{CC} = 3.3V$, $T_A = 25^{\circ}C$.
- 3. Applies to bushold versions only (74LVTH574).
- 4. An external driver must source at least the specified current to switch from LOW-to-HIGH.
- 5. An external driver must sink at least the specified current to switch from HIGH-to-LOW.
- 6. This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics⁽⁷⁾

			Conditions	Conditions T _A = 25°C		2	
Symbol	Parameter	V _{CC} (V)	$C_L = 50 pF, R_L = 500 \Omega$	Min.	Тур.	Max.	Units
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3	(8)		0.8		V
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	3.3	(8)		-0.8		V

Notes:

- 7. Characterized in SOIC package. Guaranteed parameter, but not tested.
- 8. Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

					-40°C to · 0pF, R _L =			
			V _{CC}	= 3.3V ±	0.3V	V _{CC} =	= 2.7V	
Symbol	Parameter	Mi	in.	Typ. ⁽⁹⁾	Max.	Min.	Max.	Units
f _{MAX}	Maximum Clock Frequency	15	50			150		MHz
t _{PHL}	Propagation Delay, CP to O _n	1	.8		4.6	1.8	5.3	ns
t _{PLH}		1	.8		4.5	1.8	5.3	
t _{PZL}	Output Enable Time	1	.5		5.2	1.5	6.1	ns
t _{PZH}		1	.5		4.8	1.5	5.9	
t _{PLZ}	Output Disable Time	2	.0		4.4	2.0	4.4	ns
t _{PHZ}		2	.0		4.8	2.0	5.1	
t _S	Setup Time	2	.0			2.4		ns
t _H	Hold Time	0	.3			0.0		ns
t _W	Pulse Width	3	.3			3.3		ns
t _{OSHL} , t _{OSLH}	Output to Output Skew ⁽¹⁰⁾				1.0		1.0	ns

Notes:

- 9. All typical values are at $V_{CC} = 3.3V$, $T_A = 25$ °C.
- 10. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance⁽¹¹⁾

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V or V_{CC}$	4	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_{O} = 0V$ or V_{CC}	6	pF

Note:

11. Capacitance is measured at frequency f = 1MHz, per MIL-STD-883, Method 3012.

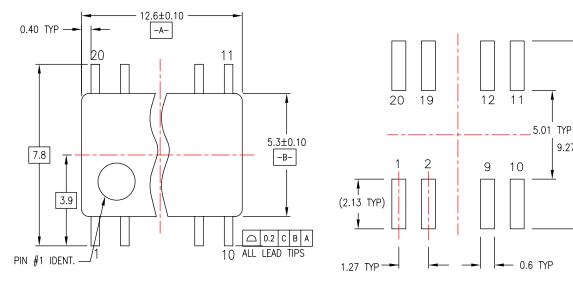
Physical Dimensions 13.00 12.60 11.43 В 9.50 10.65 7.60 10.00 7.40 PIN ONE 0.35 INDICATOR **⊕** 0.25 **M** C B A LAND PATTERN RECOMMENDATION 2.65 MAX SEE DETAIL A 0.33 0.20 △ 0.10 C 0.30 0.10 0.75 0.25 × 45° SEATING PLANE NOTES: UNLESS OTHERWISE SPECIFIED (R0.10) A) THIS PACKAGE CONFORMS TO JEDEC GAGE PLANE MS-013, VARIATION AC, ISSUE E (R0.10) B) ALL DIMENSIONS ARE IN MILLIMETERS. 0.25 C) DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS. D) CONFORMS TO ASME Y14.5M-1994 0.40 SEATING PLANE E) LANDPATTERN STANDARD: SOIC127P1030X265-20L (1.40)DETAIL A F) DRAWING FILENAME: MKT-M20BREV3

Figure 1. 20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide

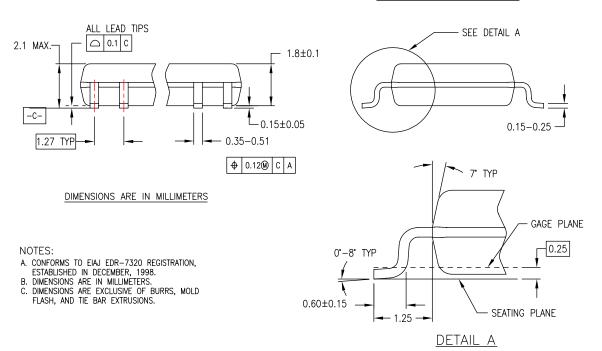
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9.27 TYP

Physical Dimensions (Continued)





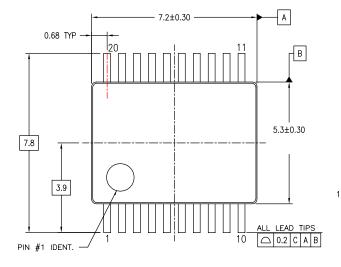


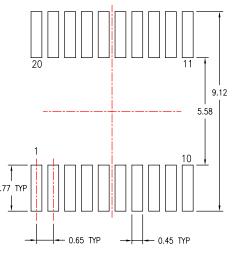
M20DREVC

Figure 2. 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide

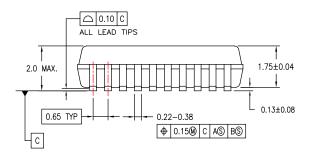
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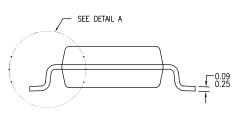
Physical Dimensions (Continued)





LAND PATTERN RECOMMENDATIONS

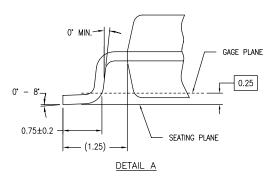




DIMENSIONS ARE IN MILLIMETERS

NOTES:

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- D. DIMENSIONS AND TOLERANCES PER ASME Y14.5M 1994.

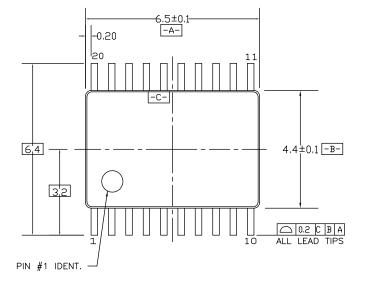


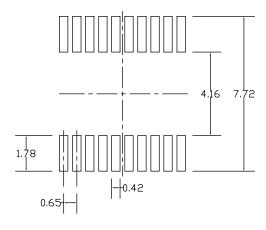
MSA20REVB

Figure 3. 20-Lead Shrink Small Outline Package (SSOP), JEDEC MO-150, 5.3mm Wide

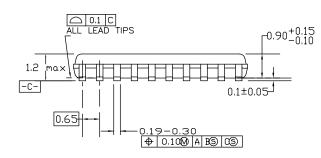
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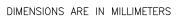
Physical Dimensions (Continued)





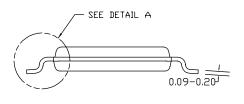
LAND PATTERN RECOMMENDATION

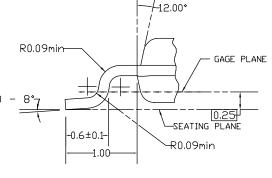




NOTES:

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- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.





DETAIL A

MTC20REVD1

Figure 4. 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

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